

XP1507

Silicon NPN epitaxial planer transistor

High breakdown voltage and for low noise amplification

Features

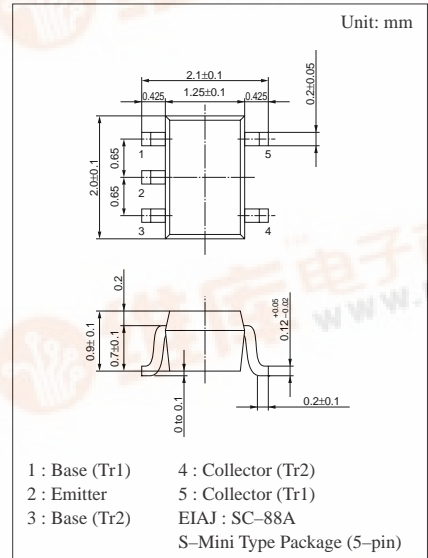
- Two elements incorporated into one package.
(Emitter-coupled transistors)
- Reduction of the mounting area and assembly cost by one half.

Basic Part Number of Element

- 2SD814 × 2 elements

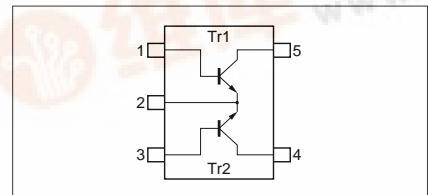
Absolute Maximum Ratings (Ta=25°C)

| | Parameter | Symbol | Ratings | Unit |
|-------------------|------------------------------|-----------|-------------|------|
| Rating of element | Collector to base voltage | V_{CBO} | 150 | V |
| | Collector to emitter voltage | V_{CEO} | 150 | V |
| | Emitter to base voltage | V_{EBO} | 5 | V |
| | Collector current | I_C | 50 | mA |
| | Peak collector current | I_{CP} | 100 | mA |
| Overall | Total power dissipation | P_T | 150 | mW |
| | Junction temperature | T_j | 150 | °C |
| | Storage temperature | T_{stg} | -55 to +150 | °C |



Marking Symbol: 40

Internal Connection

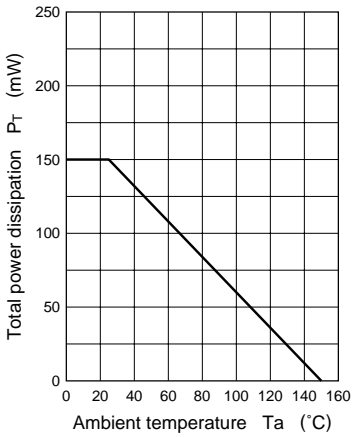


Electrical Characteristics (Ta=25°C)

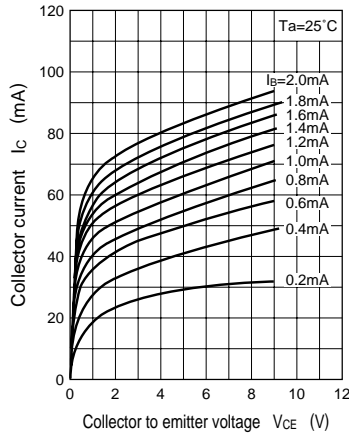
| Parameter | Symbol | Conditions | min | typ | max | Unit |
|---|-----------------------------|---|-----|------|-----|---------|
| Collector to emitter voltage | V_{CEO} | $I_C = 100\mu A, I_B = 0$ | 150 | | | V |
| Emitter to base voltage | V_{EBO} | $I_E = 10\mu A, I_C = 0$ | 5 | | | V |
| Collector cutoff current | I_{CBO} | $V_{CB} = 100V, I_E = 0$ | | | 1 | μA |
| Forward current transfer ratio | h_{FE} | $V_{CE} = 5V, I_C = 10mA$ | 90 | | 450 | |
| Forward current transfer h_{FE} ratio | $h_{FE} (small/large)^{*1}$ | $V_{CE} = 5V, I_C = 10mA$ | 0.5 | 0.99 | | |
| Collector to emitter saturation voltage | $V_{CE(sat)}$ | $I_C = 30mA, I_B = 3mA$ | | | 1 | V |
| Transition frequency | f_T | $V_{CB} = 10V, I_E = -10mA, f = 200MHz$ | | 150 | | MHz |
| Collector output capacitance | C_{ob} | $V_{CB} = 10V, I_E = 0, f = 1MHz$ | | 2.3 | | pF |

*1 Ratio between 2 elements

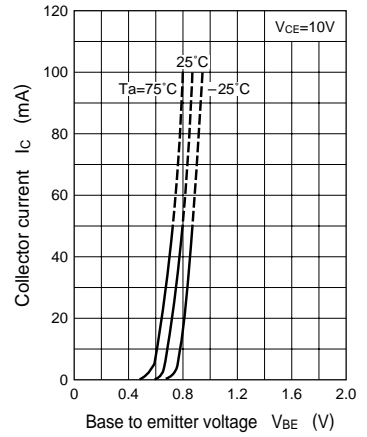
$P_T - T_a$



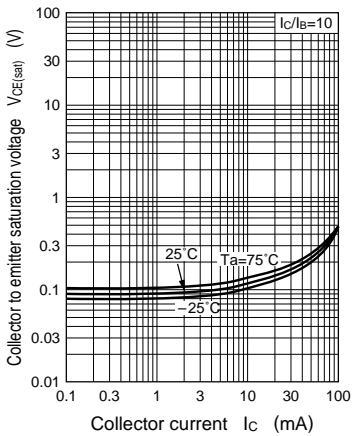
$I_C - V_{CE}$



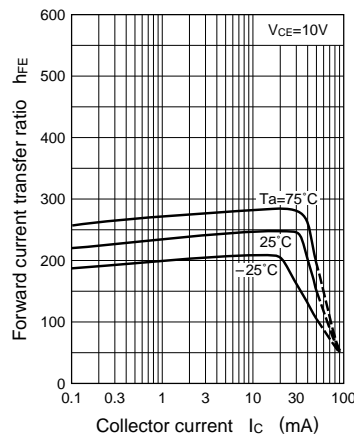
$I_C - V_{BE}$



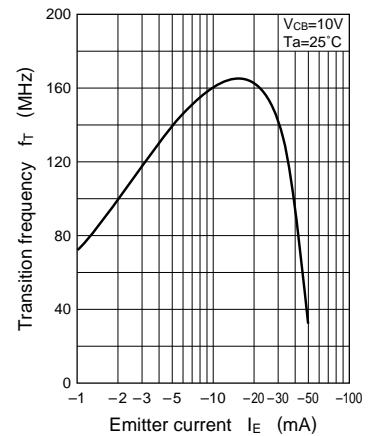
$V_{CE(sat)} - I_C$



$h_{FE} - I_C$



$f_T - I_E$



$C_{ob} - V_{CB}$

